Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-462-9585

Inclosure Material:
Ceramic
Overall Length:
Between 1.397 inches and 1.651 inches
Overall Diameter:
Between 2.997 inches and 3.150 inches
Mounting Method:
Press fit
Features Provided:
W/heat sink
Semiconductor Material:
Germanium
Voltage Rating In Volts Per Characteristic:
0.110 forward voltage, average
Current Rating Per Characteristic:
3.00 milliamperes forward current, average
Capacitance Rating In Picofarads:
0.3
Maximum Operating Tempurature Per Measurement Point:
110.0 degrees celsius ambient air
Special Features:
Series resistance 6.5 ohms
Terminal Type And Quantity:
2 binding post
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0